



# LM3488/-Q1 Automotive High-Efficiency Controller for Boost, SEPIC and Fly-Back DC-DC Converters

## 1 Features

- Automotive Grade Product, AEC-Q100 Qualified
- 8-Lead VSSOP Package
- Internal Push-Pull Driver With 1-A Peak Current Capability
- Current Limit and Thermal Shutdown
- Frequency Compensation Optimized With a Capacitor and a Resistor
- Internal Soft-Start
- Current Mode Operation
- Undervoltage Lockout With Hysteresis
- Key Specifications:
  - Wide Supply Voltage Range of 2.97 V to 40 V
  - 100-kHz to 1-MHz Adjustable and Synchronizable Clock Frequency
  - $\pm 1.5\%$  (Overtemperature) Internal Reference
  - 5- $\mu$ A Shutdown Current (Overtemperature)
- Create a Custom Design Using the LM3488 with the [WEBENCH Power Designer](#)

## 2 Applications

- Automotive Start-Stop Applications
- Automotive ADAS Driver Information
- One Cell/Two Cell Li-ion Battery Powered Portable Bluetooth Audio Systems
- Notebooks, PDAs, Digital Cameras, and other Portable Applications
- Offline Power Supplies
- Set-Top Boxes
- Boost for Audio Amplifiers

## 3 Description

The LM3488 is a versatile low-side N-FET high-performance controller for switching regulators. This device is suitable for use in topologies requiring low-side FET, such as boost, flyback, or SEPIC. Moreover, the LM3488 can be operated at extremely high switching frequency to reduce the overall solution size. The switching frequency of LM3488 can be adjusted to any value from 100 kHz to 1 MHz by using a single external resistor or by synchronizing it to an external clock. Current mode control provides superior bandwidth and transient response, besides cycle-by-cycle current limiting. Output current can be programmed with a single external resistor.

The LM3488 has built-in features such as thermal shutdown, short-circuit protection, and overvoltage protection. Power-saving shutdown mode reduces the total supply current to 5  $\mu$ A and allows power supply sequencing. Internal soft-start limits the inrush current at start-up.

### Device Information<sup>(1)</sup>

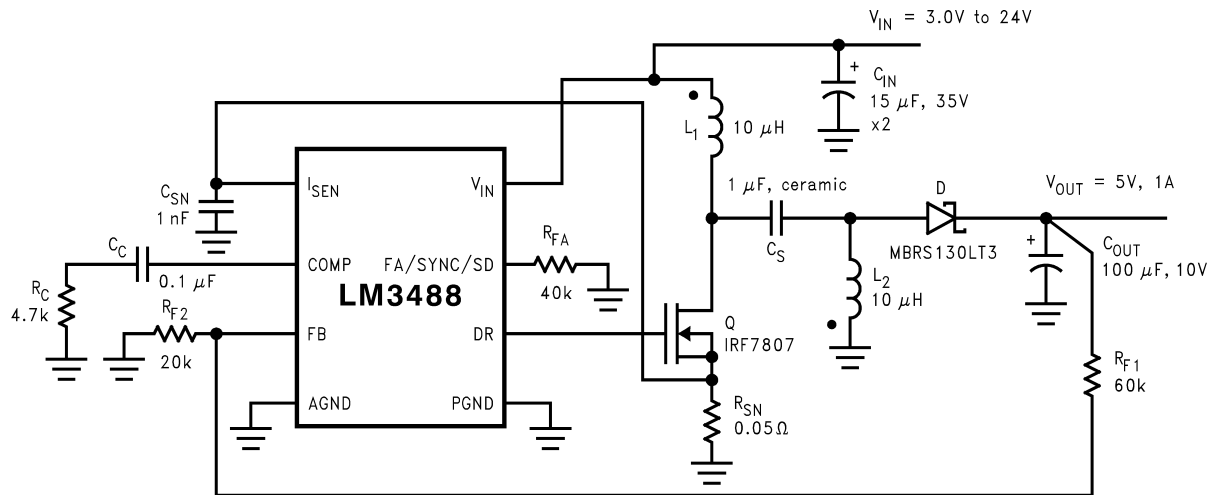
PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM3488	VSSOP (8)	3.00 mm x 3.00 mm
LM3488-Q1		

(1) For all available packages, see the orderable addendum at the end of the datasheet.



**LM3488, LM3488-Q1**

SNVS089O – JULY 2000 – REVISED JULY 2015

[www.ti.com](http://www.ti.com)
**Typical SEPIC Converter**


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## 4 Revision History

### Changes from Revision N (December 2014) to Revision O Page

• Changed Datasheet title .....	<b>1</b>
• Changed Handling Ratings to ESD Ratings .....	<b>5</b>

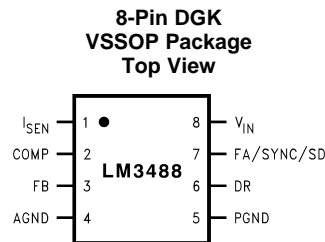
### Changes from Revision M (March 2013) to Revision N Page

• Added <i>Pin Configuration and Functions</i> section, <i>Handling Rating</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	<b>1</b>
• Changed ESD Table and Features section .....	<b>1</b>
• Changed application information. ....	<b>1</b>

### Changes from Revision L (March 2013) to Revision M Page

• Changed layout of National Data Sheet to TI format .....	<b>32</b>
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## 5 Pin Configuration and Functions



### Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
I <sub>SEN</sub>	1	I	Current sense input pin. Voltage generated across an external sense resistor is fed into this pin.
COMP	2	A	Compensation pin. A resistor, capacitor combination connected to this pin provides compensation for the control loop.
FB	3	I	Feedback pin. The output voltage should be adjusted using a resistor divider to provide 1.26 V at this pin.
AGND	4	P	Analog ground pin.
PGND	5	P	Power ground pin.
DR	6	O	Drive pin of the IC. The gate of the external MOSFET should be connected to this pin.
FA/SYNC/SD	7	A	Frequency adjust, synchronization, and Shutdown pin. A resistor connected to this pin sets the oscillator frequency. An external clock signal at this pin will synchronize the controller to the frequency of the clock. A high level on this pin for $\geq 30 \mu\text{s}$ will turn the device off. The device will then draw less than 10 $\mu\text{A}$ from the supply.
V <sub>IN</sub>	8	P	Power supply input pin.

## 6 Specifications

### 6.1 Absolute Maximum Ratings <sup>(1)</sup>

	MIN	MAX	UNIT
Input voltage		45	V
FB pin voltage	$-0.4 < V_{FB}$	$V_{FB} < 7$	V
FA/SYNC/SD pin voltage	$-0.4 < V_{FA/SYNC/SD}$	$V_{FA/SYNC/SD} < 7$	V
Peak driver output current ( $< 10 \mu\text{s}$ )		1	A
Power dissipation		Internally Limited	
Junction temperature		150	°C
Lead temperature	Vapor Phase (60 s)	215	°C
	Infrared (15 s)	260	°C
DR pin voltage	$-0.4 \leq V_{DR}$	$V_{DR} \leq 8$	V
I <sub>LIM</sub> pin voltage		600	mV

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. [Recommended Operating Conditions](#) are conditions under which operation of the device is intended to be functional. For specifications and test conditions, see the [Electrical Characteristics](#).

### 6.2 ESD Ratings : LM3488

			MIN	MAX	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	−2000	2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	−750	750	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 ESD Ratings: LM3488-Q1

			MIN	MAX	UNIT
$V_{\text{ESD}}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	–2000	2000	V
		Charged device model (CDM), per AEC Q100-011	–750	750	
		Corner pins (1, 4, 5, and 8) Other pins	–750	750	

(1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 6.4 Recommended Operating Conditions

	MIN	MAX	UNIT
Supply Voltage	$2.97 \leq V_{\text{IN}}$	$V_{\text{IN}} \leq 40$	V
Junction Temperature Range	$-40 \leq T_{\text{J}}$	$T_{\text{J}} \leq 125$	°C
Switching Frequency	$100 \leq F_{\text{SW}}$	$F_{\text{SW}} \leq 1$	kHz/MHz

### 6.5 Thermal Information

THERMAL METRIC <sup>(1)</sup>		LM3488, LM3488-Q1	UNIT
		DGK	
		8 PINS	
$R_{\theta\text{JA}}$	Junction-to-ambient thermal resistance	160	°C/W
$R_{\theta\text{JC(top)}}$	Junction-to-case (top) thermal resistance	50	
$R_{\theta\text{JB}}$	Junction-to-board thermal resistance	77	
$\Psi_{\text{JT}}$	Junction-to-top characterization parameter	4.7	
$\Psi_{\text{JB}}$	Junction-to-board characterization parameter	76	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

### 6.6 Electrical Characteristics

Unless otherwise specified,  $V_{\text{IN}} = 12 \text{ V}$ ,  $R_{\text{FA}} = 40 \text{ k}\Omega$ ,  $T_{\text{J}} = 25^\circ\text{C}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{\text{FB}}$	Feedback Voltage	$V_{\text{COMP}} = 1.4 \text{ V}$ , $2.97 \leq V_{\text{IN}} \leq 40 \text{ V}$	1.2507	1.26	1.2753	V
		$V_{\text{COMP}} = 1.4 \text{ V}$ , $2.97 \leq V_{\text{IN}} \leq 40 \text{ V}$ , $-40^\circ\text{C} \leq T_{\text{J}} \leq 125^\circ\text{C}$	1.24		1.28	
$\Delta V_{\text{LINE}}$	Feedback Voltage Line Regulation	$2.97 \leq V_{\text{IN}} \leq 40 \text{ V}$		0.001		%/V
$\Delta V_{\text{LOAD}}$	Output Voltage Load Regulation	$I_{\text{EAO}}$ Source/Sink		$\pm 0.5$		%/V (max)
$V_{\text{UVLO}}$	Input Undervoltage Lock-out			2.85		V
		$-40^\circ\text{C} \leq T_{\text{J}} \leq 125^\circ\text{C}$			2.97	
$V_{\text{UV(HYS)}}$	Input Undervoltage Lock-out Hysteresis			170		mV
		$-40^\circ\text{C} \leq T_{\text{J}} \leq 125^\circ\text{C}$	130		210	
$F_{\text{nom}}$	Nominal Switching Frequency	$R_{\text{FA}} = 40 \text{ k}\Omega$		400		kHz
		$R_{\text{FA}} = 40 \text{ k}\Omega$ , $-40^\circ\text{C} \leq T_{\text{J}} \leq 125^\circ\text{C}$	360		430	
$R_{\text{DS1 (ON)}}$	Driver Switch On Resistance (top)	$I_{\text{DR}} = 0.2 \text{ A}$ , $V_{\text{IN}} = 5 \text{ V}$		16		$\Omega$
$R_{\text{DS2 (ON)}}$	Driver Switch On Resistance (bottom)	$I_{\text{DR}} = 0.2 \text{ A}$		4.5		$\Omega$
$V_{\text{DR (max)}}$	Maximum Drive Voltage Swing <sup>(1)</sup>	$V_{\text{IN}} < 7.2 \text{ V}$		$V_{\text{IN}}$		V
		$V_{\text{IN}} \geq 7.2 \text{ V}$		7.2		
$D_{\text{max}}$	Maximum Duty Cycle <sup>(2)</sup>			100%		

(1) The voltage on the drive pin,  $V_{\text{DR}}$  is equal to the input voltage when input voltage is less than 7.2 V.  $V_{\text{DR}}$  is equal to 7.2 V when the input voltage is greater than or equal to 7.2 V.

(2) The limits for the maximum duty cycle can not be specified since the part does not permit less than 100% maximum duty cycle operation.

## Electrical Characteristics (continued)

Unless otherwise specified,  $V_{IN} = 12\text{ V}$ ,  $R_{FA} = 40\text{ k}\Omega$ ,  $T_J = 25^\circ\text{C}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$T_{min}$ (on)	Minimum On Time			325		nsec
		$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	230		550	
$I_{SUPPLY}$	Supply Current (switching)	See <sup>(3)</sup>		2.7		mA
		See <sup>(3)</sup> , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$			3.0	
$I_Q$	Quiescent Current in Shutdown Mode	$V_{FA}/\text{SYNC}/\text{SD} = 5\text{ V}^{(4)}$ , $V_{IN} = 5\text{ V}$		5		$\mu\text{A}$
		$V_{FA}/\text{SYNC}/\text{SD} = 5\text{ V}^{(4)}$ , $V_{IN} = 5\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$			7	
$V_{SENSE}$	Current Sense Threshold Voltage	$V_{IN} = 5\text{ V}$	135	156	180	mV
		$V_{IN} = 5\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	125		190	
$V_{SC}$	Short-Circuit Current Limit Sense Voltage	$V_{IN} = 5\text{ V}$		343		mV
		$V_{IN} = 5\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	250		415	
$V_{SL}$	Internal Compensation Ramp Voltage	$V_{IN} = 5\text{ V}$		92		mV
		$V_{IN} = 5\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	52		132	
$V_{SL}\text{ ratio}$	$V_{SL}/V_{SENSE}$		0.30	0.49	0.70	
$V_{OVP}$	Output Overvoltage Protection (with respect to feedback voltage) <sup>(5)</sup>	$V_{COMP} = 1.4\text{ V}$	32	50	78	mV
		$V_{COMP} = 1.4\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	25		85	
$V_{OVP}(\text{HYS})$	Output Over-Voltage Protection Hysteresis <sup>(5)</sup>	$V_{COMP} = 1.4\text{ V}$		60		mV
		$V_{COMP} = 1.4\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	20		110	
$G_m$	Error Amplifier Transconductance	$V_{COMP} = 1.4\text{ V}$ , $I_{EAO} = 100\text{ }\mu\text{A}$ (Source/Sink)	600	800	1000	$\mu\text{mho}$
		$V_{COMP} = 1.4\text{ V}$ , $I_{EAO} = 100\text{ }\mu\text{A}$ (Source/Sink), $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	365		1265	
$A_{VOL}$	Error Amplifier Voltage Gain	$V_{COMP} = 1.4\text{ V}$ , $I_{EAO} = 100\text{ }\mu\text{A}$ (Source/Sink)		38		V/V
		$V_{COMP} = 1.4\text{ V}$ , $I_{EAO} = 100\text{ }\mu\text{A}$ (Source/Sink), $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	26		44	
$I_{EAO}$	Error Amplifier Output Current (Source/Sink)	Source, $V_{COMP} = 1.4\text{ V}$ , $V_{FB} = 0\text{ V}$	80	110	140	$\mu\text{A}$
		Source, $V_{COMP} = 1.4\text{ V}$ , $V_{FB} = 0\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	50		180	
		Sink, $V_{COMP} = 1.4\text{ V}$ , $V_{FB} = 1.4\text{ V}$	-100	-140	-180	$\mu\text{A}$
		Sink, $V_{COMP} = 1.4\text{ V}$ , $V_{FB} = 1.4\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	-85		-185	
$V_{EAO}$	Error Amplifier Output Voltage Swing	Upper Limit: $V_{FB} = 0\text{ V}$ , COMP Pin = Floating		2.2		V
		Upper Limit: $V_{FB} = 0\text{ V}$ , COMP Pin = Floating, $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	1.8		2.4	
		Lower Limit: $V_{FB} = 1.4\text{ V}$		0.56		V
		Lower Limit: $V_{FB} = 1.4\text{ V}$ , $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	0.2		1.0	
$T_{SS}$	Internal Soft-Start Delay	$V_{FB} = 1.2\text{ V}$ , $V_{COMP} = \text{Floating}$		4		ms
$T_r$	Drive Pin Rise Time	$C_{gs} = 3000\text{ pf}$ , $V_{DR} = 0\text{ to }3\text{ V}$		25		ns
$T_f$	Drive Pin Fall Time	$C_{gs} = 3000\text{ pf}$ , $V_{DR} = 0\text{ to }3\text{ V}$		25		ns

(3) For this test, the FA/SYNC/SD Pin is pulled to ground using a 40K resistor .

(4) For this test, the FA/SYNC/SD Pin is pulled to 5 V using a 40K resistor.

(5) The over-voltage protection is specified with respect to the feedback voltage. This is because the over-voltage protection tracks the feedback voltage. The over-voltage threshold can be calculated by adding the feedback voltage,  $V_{FB}$  to the over-voltage protection specification.

## Electrical Characteristics (continued)

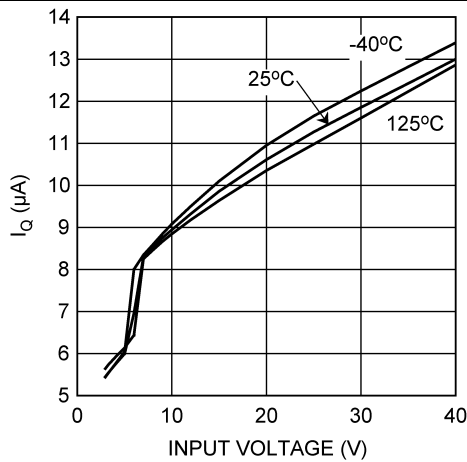
Unless otherwise specified,  $V_{IN} = 12\text{ V}$ ,  $R_{FA} = 40\text{ k}\Omega$ ,  $T_J = 25^\circ\text{C}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VSD	Shutdown and Synchronization signal threshold <sup>(6)</sup>	Output = High		1.27		V
		Output = High, $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$			1.4	
		Output = Low		0.65		V
		Output = Low, $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		0.3		
I <sub>SD</sub>	Shutdown Pin Current	$V_{SD} = 5\text{ V}$		-1		$\mu\text{A}$
		$V_{SD} = 0\text{ V}$		+1		
I <sub>FB</sub>	Feedback Pin Current			15		nA
TSD	Thermal Shutdown			165		$^\circ\text{C}$
T <sub>sh</sub>	Thermal Shutdown Hysteresis			10		$^\circ\text{C}$

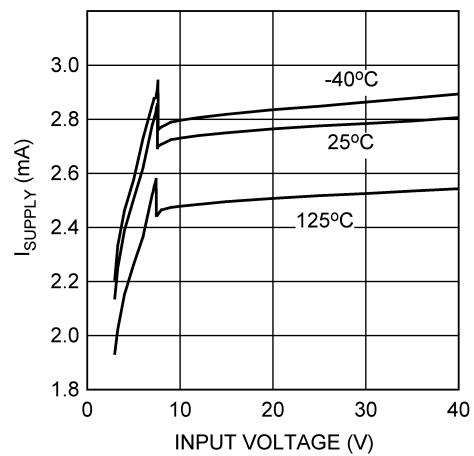
(6) The FA/SYNC/SD pin should be pulled to  $V_{IN}$  through a resistor to turn the regulator off.

## 6.7 Typical Characteristics

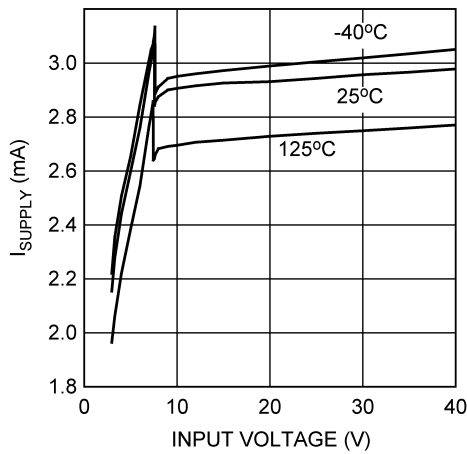
Unless otherwise specified,  $V_{IN} = 12V$ ,  $T_J = 25^\circ C$ .



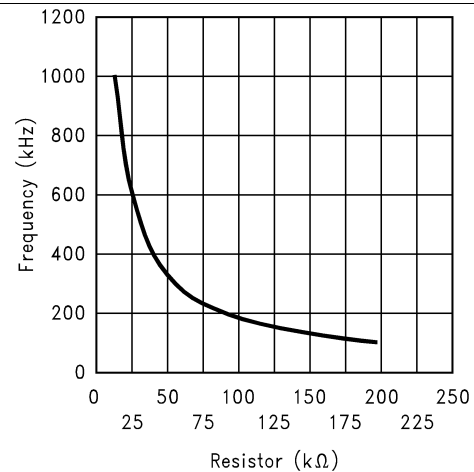
**Figure 1.  $I_Q$  vs Temperature & Input Voltage**



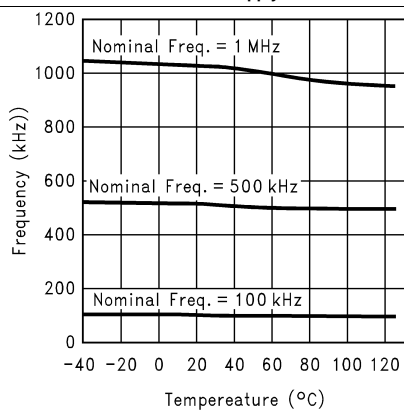
**Figure 2.  $I_{Supply}$  vs Input Voltage (Non-Switching)**



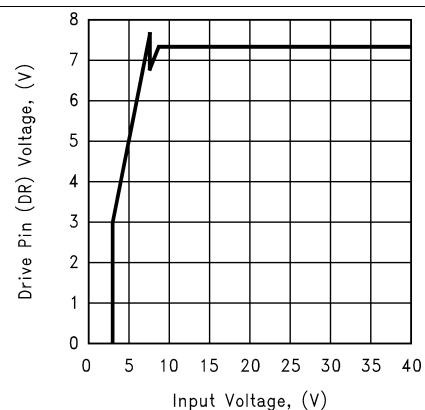
**Figure 3.  $I_{Supply}$  vs  $V_{IN}$**



**Figure 4. Switching Frequency vs RFA**



**Figure 5. Frequency vs Temperature**

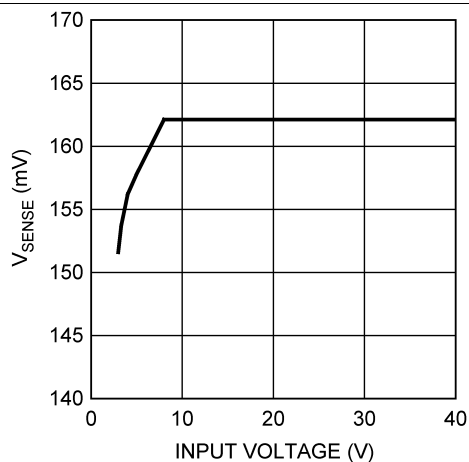


**Figure 6. Drive Voltage vs Input Voltage**

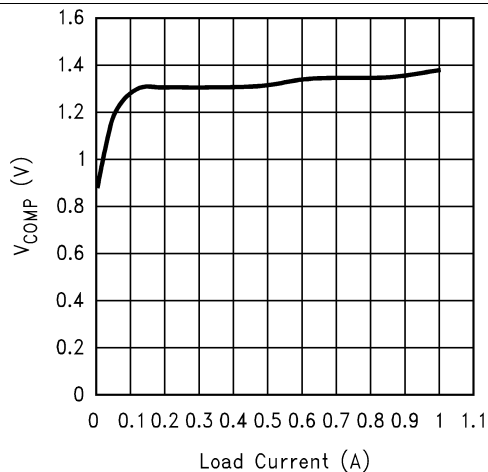


## Typical Characteristics (continued)

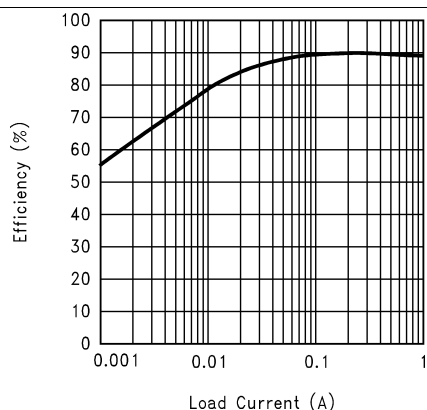
Unless otherwise specified,  $V_{IN} = 12V$ ,  $T_J = 25^\circ C$ .



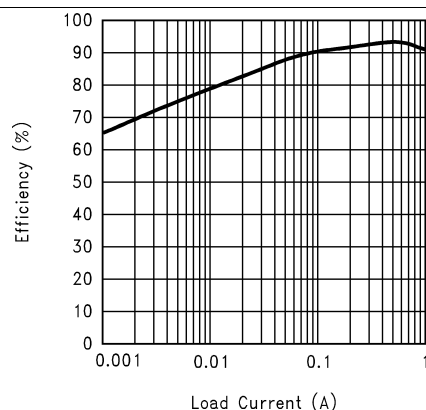
**Figure 7. Current Sense Threshold vs Input Voltage**



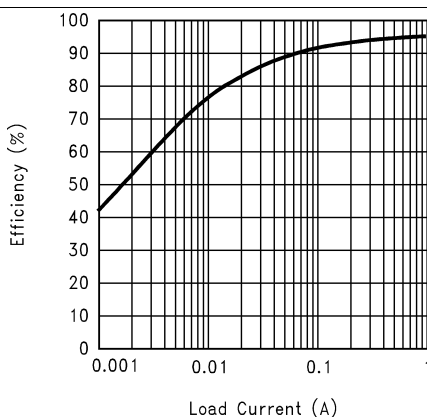
**Figure 8. COMP Pin Voltage vs Load Current**



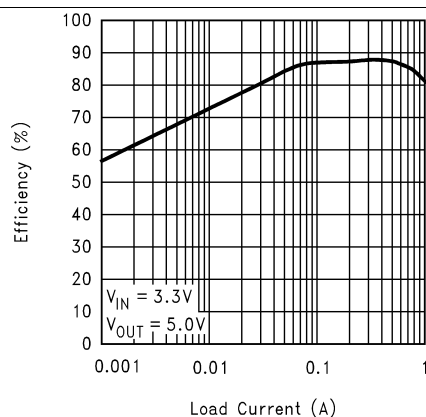
**Figure 9. Efficiency vs Load Current (3.3 V In and 12 V Out)**



**Figure 10. Efficiency vs Load Current (5 V In and 12 V Out)**



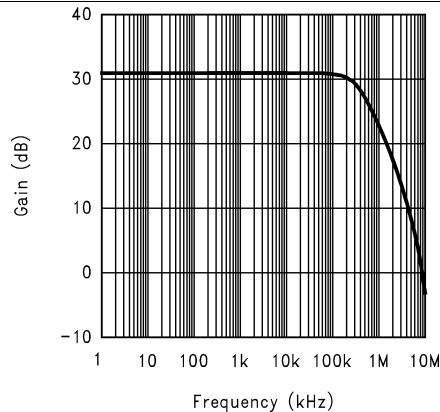
**Figure 11. Efficiency vs Load Current (9 V In and 12 V Out)**



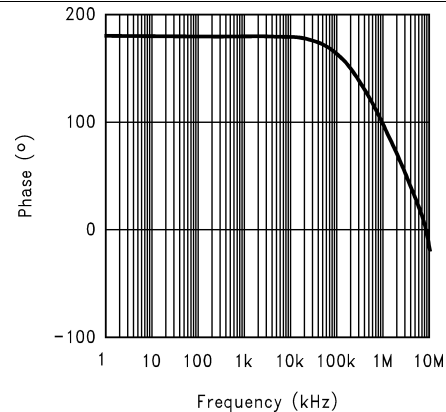
**Figure 12. Efficiency vs Load Current (3.3 V In and 5 V Out)**

## Typical Characteristics (continued)

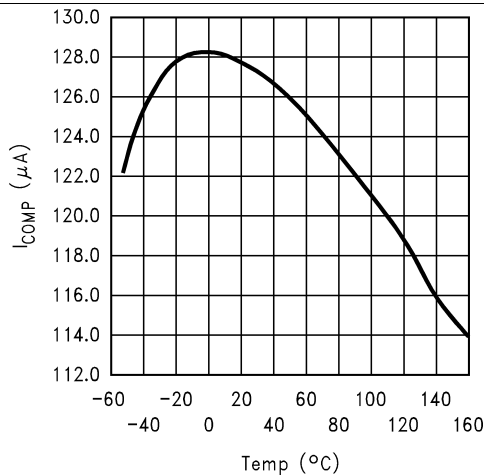
Unless otherwise specified,  $V_{IN} = 12V$ ,  $T_J = 25^\circ C$ .



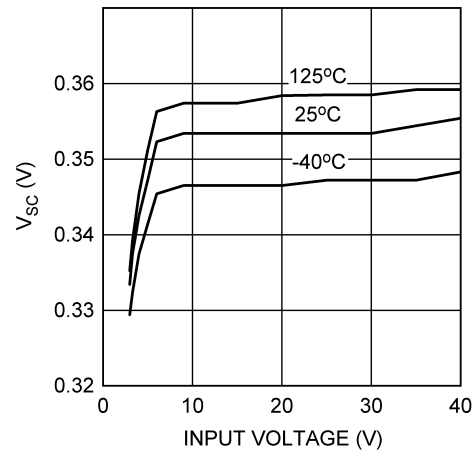
**Figure 13. Error Amplifier Gain**



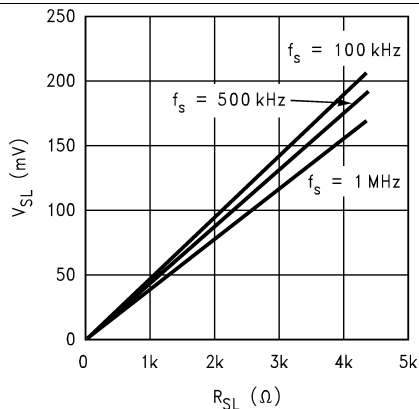
**Figure 14. Error Amplifier Phase**



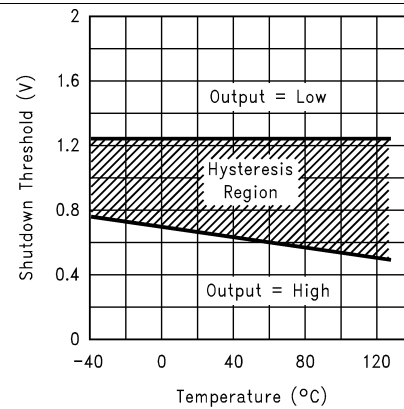
**Figure 15. COMP Pin Source Current vs Temperature**



**Figure 16. Short Circuit Protection vs Input Voltage**



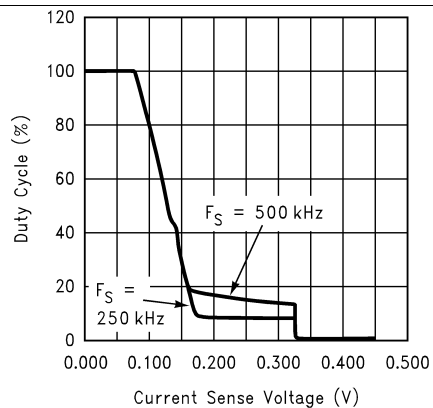
**Figure 17. Compensation Ramp vs Compensation Resistor**



**Figure 18. Shutdown Threshold Hysteresis vs Temperature**

## Typical Characteristics (continued)

Unless otherwise specified,  $V_{IN} = 12V$ ,  $T_J = 25^\circ C$ .



**Figure 19. Current Sense Voltage vs Duty Cycle**

## 7 Detailed Description

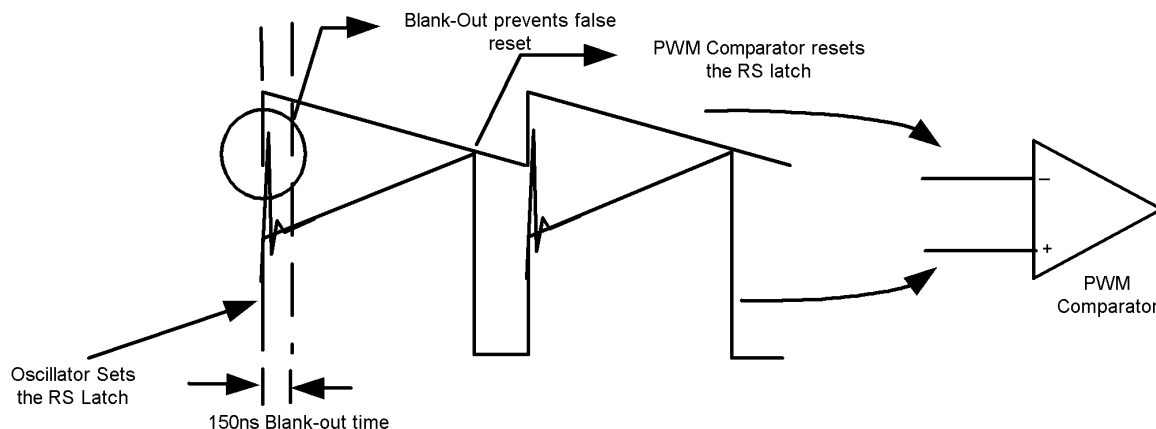
### 7.1 Overview

The LM3488 uses a fixed frequency, Pulse Width Modulated (PWM), current mode control architecture. In a typical application circuit, the peak current through the external MOSFET is sensed through an external sense resistor. The voltage across this resistor is fed into the  $I_{SEN}$  pin. This voltage is then level shifted and fed into the positive input of the PWM comparator. The output voltage is also sensed through an external feedback resistor divider network and fed into the error amplifier negative input (feedback pin, FB). The output of the error amplifier (COMP pin) is added to the slope compensation ramp and fed into the negative input of the PWM comparator.

At the start of any switching cycle, the oscillator sets the RS latch using the SET/Blank-out and switch logic blocks. This forces a high signal on the DR pin (gate of the external MOSFET) and the external MOSFET turns on. When the voltage on the positive input of the PWM comparator exceeds the negative input, the RS latch is reset and the external MOSFET turns off.

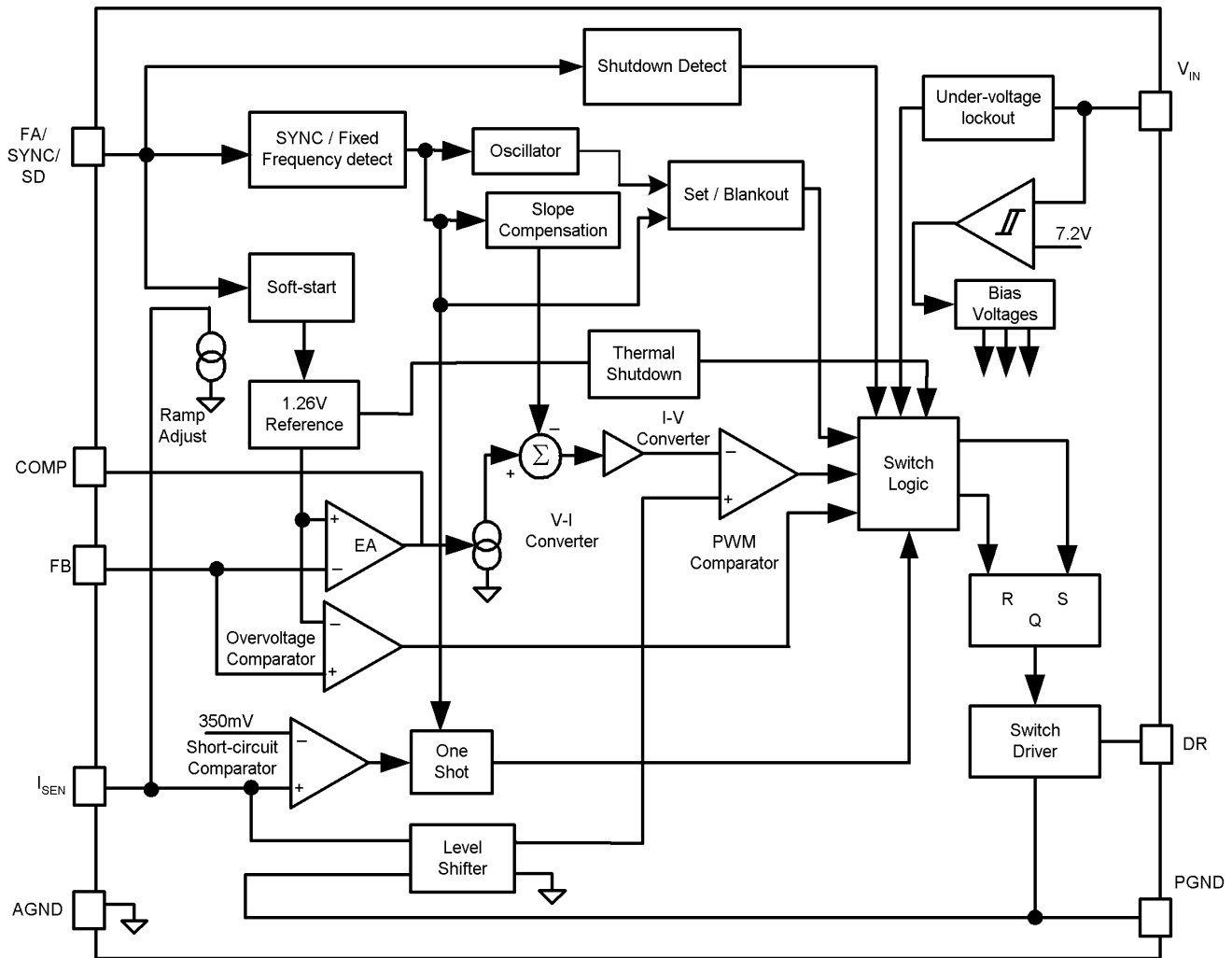
The voltage sensed across the sense resistor generally contains spurious noise spikes, as shown in [Figure 20](#). These spikes can force the PWM comparator to reset the RS latch prematurely. To prevent these spikes from resetting the latch, a blank-out circuit inside the IC prevents the PWM comparator from resetting the latch for a short duration after the latch is set. This duration is about 150ns and is called the blank-out time.

Under extremely light load or no-load conditions, the energy delivered to the output capacitor when the external MOSFET is on during the blank-out time is more than what is delivered to the load. An over-voltage comparator inside the LM3488 prevents the output voltage from rising under these conditions. The over-voltage comparator senses the feedback (FB pin) voltage and resets the RS latch under these conditions. The latch remains in reset state till the output decays to the nominal value.



**Figure 20. Basic Operation of the PWM Comparator**

## 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Slope Compensation Ramp

The LM3488 uses a current mode control scheme. The main advantages of current mode control are inherent cycle-by-cycle current limit for the switch, and simpler control loop characteristics. It is also easy to parallel power stages using current mode control since as current sharing is automatic.

Current mode control has an inherent instability for duty cycles greater than 50%, as shown in [Figure 21](#). In [Figure 21](#), a small increase in the load current causes the switch current to increase by  $\Delta I_O$ . The effect of this load change,  $\Delta I_1$ , is :

$$\Delta I_1 = -\left(\frac{M_2}{M_1}\right) \Delta I_O = -\left(\frac{D}{1-D}\right) \Delta I_O \quad (1)$$

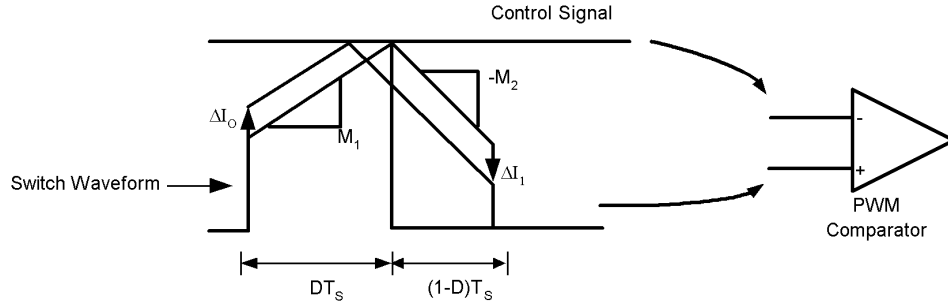
From the above equation, when  $D > 0.5$ ,  $\Delta I_1$  will be greater than  $\Delta I_O$ . In other words, the disturbance is divergent. So a very small perturbation in the load will cause the disturbance to increase.

To prevent the sub-harmonic oscillations, a compensation ramp is added to the control signal, as shown in [Figure 22](#).

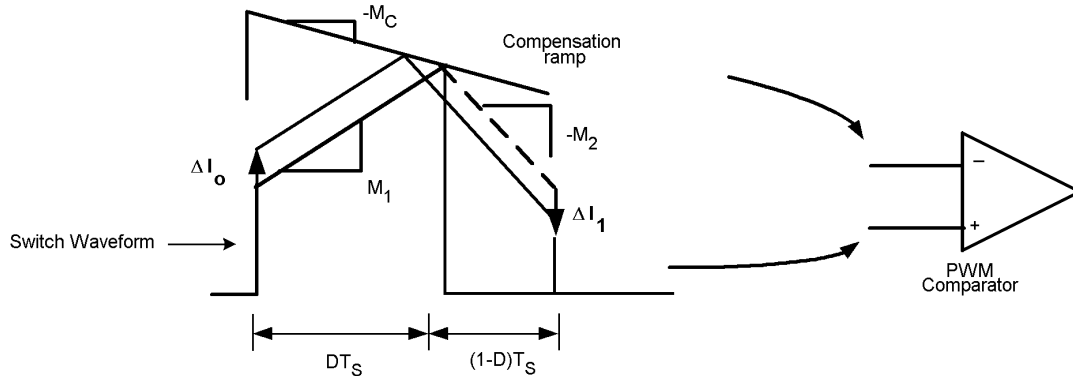
## Feature Description (continued)

With the compensation ramp,

$$\Delta I_1 = - \left( \frac{M_2 - M_C}{M_1 + M_C} \right) \Delta I_0 \quad (2)$$



**Figure 21. Sub-Harmonic Oscillation for D>0.5**



**Figure 22. Compensation Ramp Avoids Sub-Harmonic Oscillation**

The compensation ramp has been added internally in LM3488. The slope of this compensation ramp has been selected to satisfy most of the applications. The slope of the internal compensation ramp depends on the frequency. This slope can be calculated using the formula:

$$M_C = V_{SL} \cdot F_S \text{ Volts/second} \quad (3)$$

In the above equation,  $V_{SL}$  is the amplitude of the internal compensation ramp. Limits for  $V_{SL}$  have been specified in the electrical characteristics.

In order to provide the user additional flexibility, a patented scheme has been implemented inside the IC to increase the slope of the compensation ramp externally, if the need arises. Adding a single external resistor,  $R_{SL}$  (as shown in [Figure 23](#)) increases the slope of the compensation ramp,  $M_C$  by :

$$\Delta M_C = \frac{40 \times 10^{-6} \cdot R_{SL} \cdot F_S}{R_{SEN}} \frac{\text{Amps}}{\text{second}} \quad (4)$$

In this equation,  $\Delta V_{SL}$  is equal to  $40 \cdot 10^{-6} R_{SL}$ . Hence,

$$\Delta M_C = \frac{\Delta V_{SL} \cdot F_S}{R_{SEN}} \frac{\text{Amps}}{\text{second}} \quad (5)$$

$\Delta V_{SL}$  versus  $R_{SL}$  has been plotted in [Figure 24](#) for different frequencies.

## Feature Description (continued)

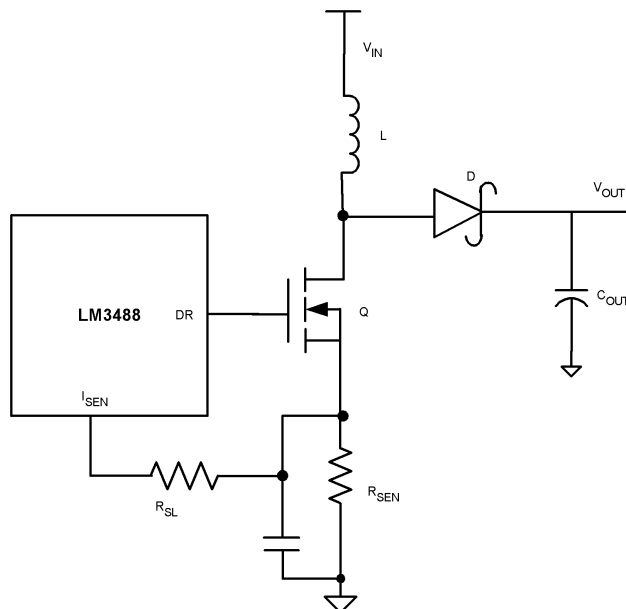


Figure 23. Increasing the Slope of the Compensation Ramp

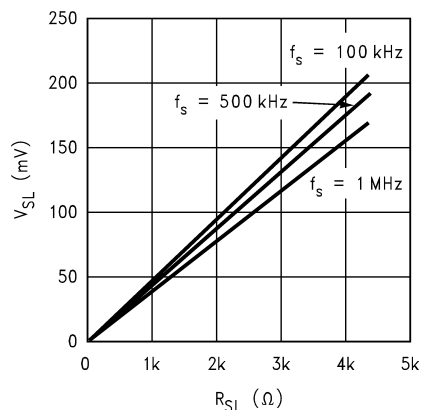


Figure 24.  $\Delta V_{SL}$  vs  $R_{SL}$

### 7.3.2 Frequency Adjust/Synchronization/Shutdown

The switching frequency of LM3488 can be adjusted between 100kHz and 1MHz using a single external resistor. This resistor must be connected between FA/SYNC/SD pin and ground, as shown in [Figure 25](#). See [Typical Characteristics](#) to determine the value of the resistor required for a desired switching frequency.

The LM3488 can be synchronized to an external clock. The external clock must be connected to the FA/SYNC/SD pin through a resistor,  $R_{SYNC}$  as shown in [Figure 26](#). The value of this resistor is dependent on the off time of the synchronization pulse,  $T_{OFF(SYNC)}$ . [Table 1](#) shows the range of resistors to be used for a given  $T_{OFF(SYNC)}$ .

Table 1. Recommended Series Resistance for Synchronization

$T_{OFF(SYNC)}$ ( $\mu$ s)	$R_{SYNC}$ range (k $\Omega$ )
1	5 to 13
2	20 to 40

**Table 1. Recommended Series Resistance for Synchronization (continued)**

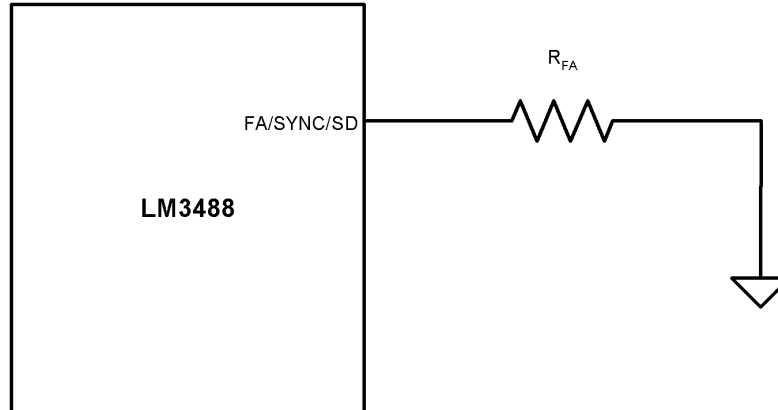
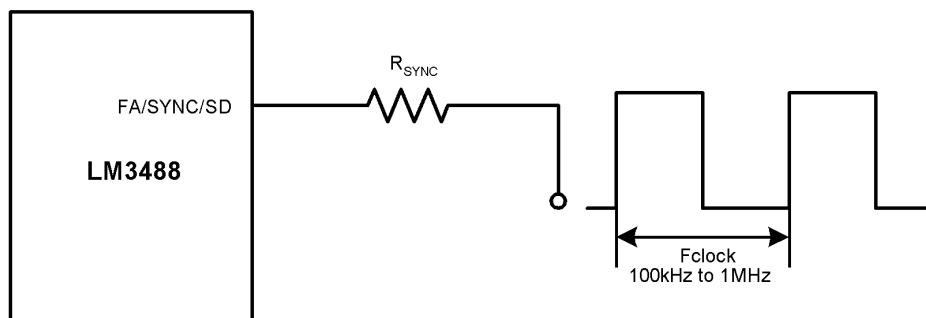
$T_{OFF(SYNC)}$ ( $\mu s$ )	$R_{SYNC}$ range ( $k\Omega$ )
3	40 to 65
4	55 to 90
5	70 to 110
6	85 to 140
7	100 to 160
8	120 to 190
9	135 to 215
10	150 to 240

It is also necessary to have the width of the synchronization pulse wider than the duty cycle of the converter (when DR pin is high and the switching point is low). It is also necessary to have the synchronization pulse width  $\geq 300nsecs$ .

The FA/SYNC/SD pin also functions as a shutdown pin. If a high signal (see [Electrical Characteristics](#) for definition of high signal) appears on the FA/SYNC/SD pin, the LM3488 stops switching and goes into a low current mode. The total supply current of the IC reduces to less than  $10\mu A$  under these conditions.

[Figure 27](#) and [Figure 28](#) show implementation of shutdown function when operating in Frequency adjust mode and synchronization mode respectively. In frequency adjust mode, connecting the FA/SYNC/SD pin to ground forces the clock to run at a certain frequency. Pulling this pin high shuts down the IC. In frequency adjust or synchronization mode, a high signal for more than  $30\mu s$  shuts down the IC.

[Figure 29](#) shows implementation of both frequency adjust with  $R_{FA}$  resistor and frequency synchronization with  $R_{SYNC}$ . The switching frequency is defined by  $R_{FA}$  when a synchronization signal is not applied. When sync is applied it overrides the  $R_{FA}$  setting.


**Figure 25. Frequency Adjust**

**Figure 26. Frequency Synchronization**



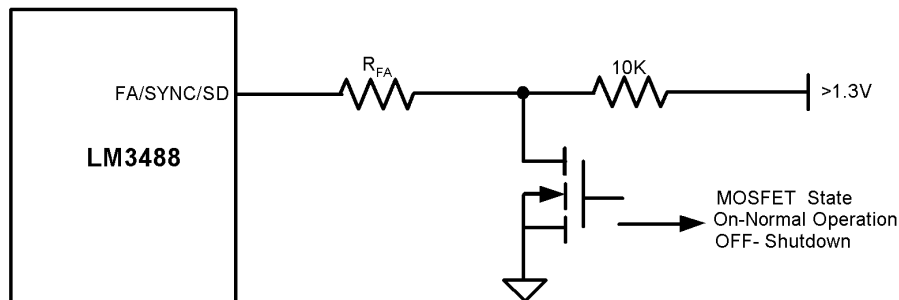


Figure 27. Shutdown Operation in Frequency Adjust Mode

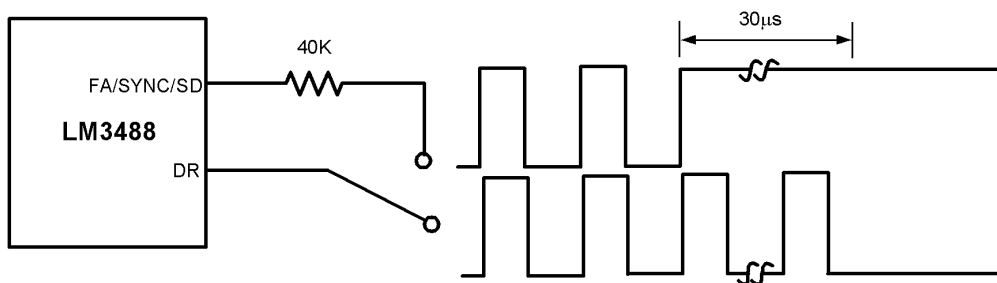


Figure 28. Shutdown Operation in Synchronization Mode

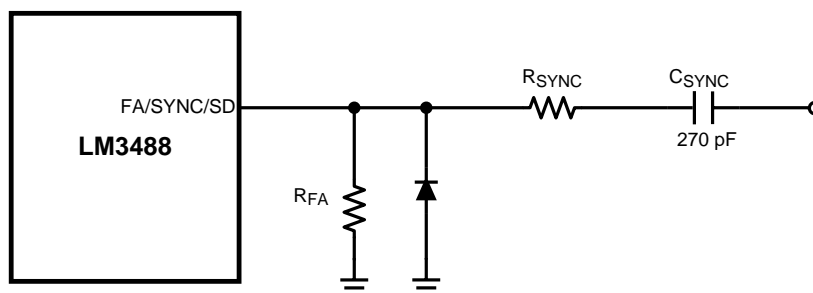


Figure 29. Frequency Adjust or Frequency Synchronization

### 7.3.3 Short-Circuit Protection

When the voltage across the sense resistor (measured on  $I_{SEN}$  Pin) exceeds 350mV, short-circuit current limit gets activated. A comparator inside LM3488 reduces the switching frequency by a factor of 5 and maintains this condition till the short is removed.

## 7.4 Device Functional Modes

The device is set to run as soon as the input voltage crosses above the UVLO set point and at a frequency set according to the FA/SYNC/SD pin pull-down resistor or to run at a frequency set by the waveform applied to the FA/SYNC/SD pin.

If the FA/SYNC/SD pin is pulled high, the LM3488 enters shut-down mode.

If the voltage at the  $I_{SEN}$  pin exceeds  $V_{SC}$ , the device enters short-circuit protection mode.

## 8 Application and Implementation

### NOTE

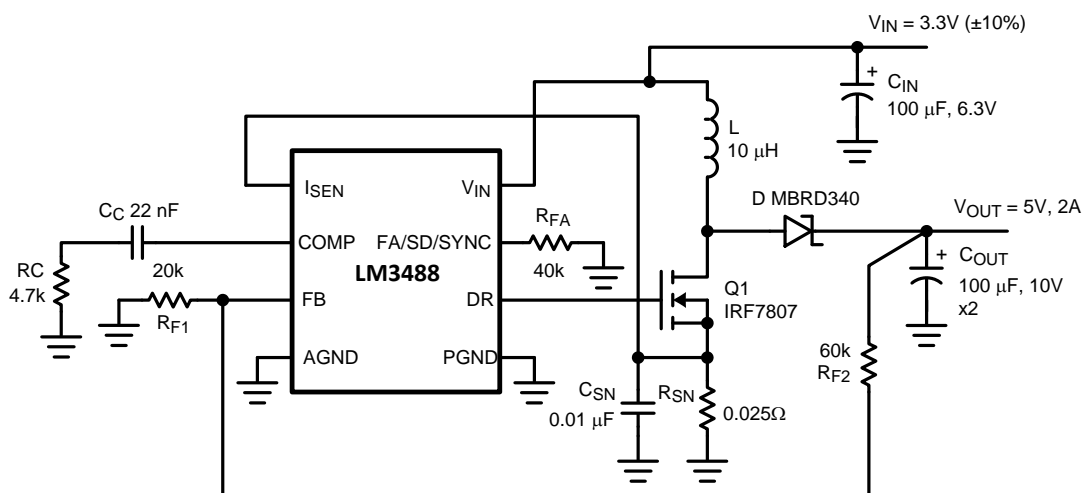
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The LM3488 may be operated in either continuous or discontinuous conduction mode. The following applications are designed for continuous conduction operation. This mode of operation has higher efficiency and lower EMI characteristics than the discontinuous mode.

### 8.2 Typical Applications

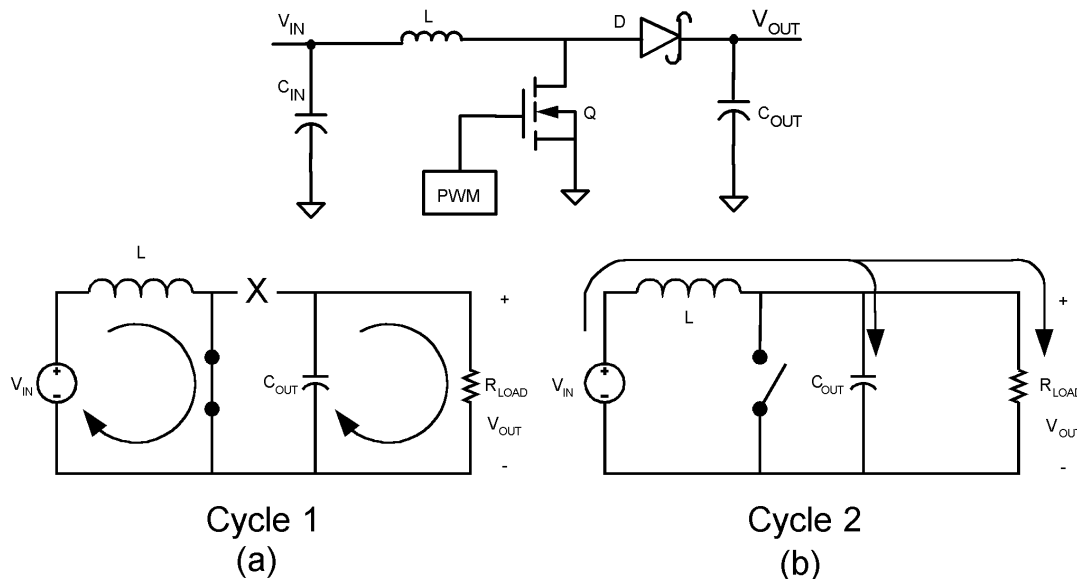
#### 8.2.1 Boost Converter



**Figure 30. Typical High Efficiency Step-Up (Boost) Converter**

The most common topology for LM3488 is the boost or step-up topology. The boost converter converts a low input voltage into a higher output voltage. The basic configuration for a boost regulator is shown in [Figure 31](#). In continuous conduction mode (when the inductor current never reaches zero at steady state), the boost regulator operates in two cycles. In the first cycle of operation, MOSFET Q is turned on and energy is stored in the inductor. During this cycle, diode D is reverse biased and load current is supplied by the output capacitor,  $C_{OUT}$ .

## Typical Applications (continued)



**Figure 31. Simplified Boost Converter Diagram**  
(a) First cycle of operation  
(b) Second cycle of operation

In the second cycle, MOSFET Q is off and the diode is forward biased. The energy stored in the inductor is transferred to the load and output capacitor. The ratio of these two cycles determines the output voltage. The output voltage is defined as:

$$V_{OUT} = \frac{V_{IN}}{1-D} \quad (6)$$

(ignoring the drop across the MOSFET and the diode), or

$$V_{OUT} + V_D = \frac{V_{IN} - V_Q}{1-D}$$

where

- D is the duty cycle of the switch
  - $V_D$  is the forward voltage drop of the diode
  - $V_Q$  is the drop across the MOSFET when it is on
- (7)

### 8.2.1.1 Design Requirements

To calculate component values for a Boost converter, the power supply parameters shown in [Table 2](#) should be known. The design shown in [Figure 30](#) is the result of starting with example values shown in [Table 2](#).

**Table 2. Boost Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	3V to 3.6V
Output voltage	5V
Maximum current	2A
Operating frequency	350kHz

## 8.2.1.2 Detailed Design Procedure

### 8.2.1.2.1 Custom Design with WEBENCH Tools

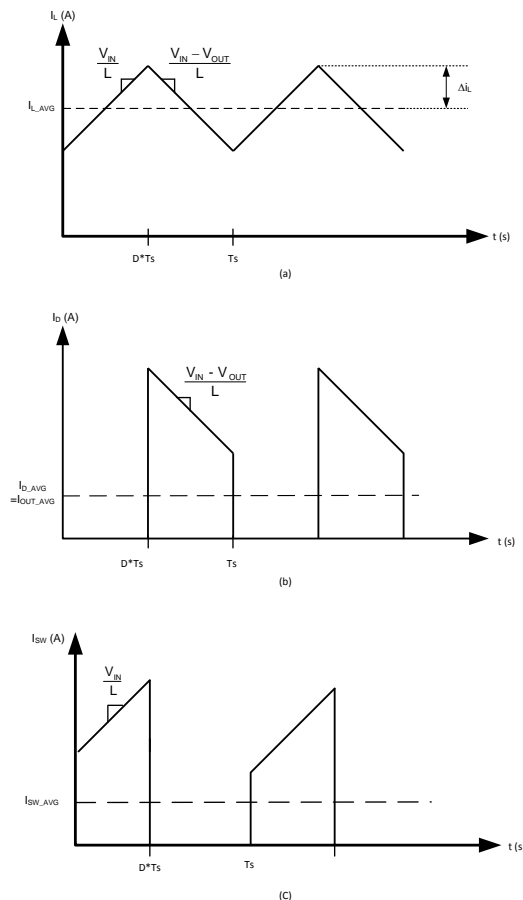
[Click here](#) to create a custom design using the LM3488 device with the WEBENCH® Power Designer.

1. Start by entering your  $V_{IN}$ ,  $V_{OUT}$  and  $I_{OUT}$  requirements.
2. Optimize your design for key parameters like efficiency, footprint and cost using the optimizer dial and compare this design with other possible solutions from Texas Instruments.
3. WEBENCH Power Designer provides you with a customized schematic along with a list of materials with real time pricing and component availability.
4. In most cases, you will also be able to:
  - Run electrical simulations to see important waveforms and circuit performance,
  - Run thermal simulations to understand the thermal performance of your board,
  - Export your customized schematic and layout into popular CAD formats,
  - Print PDF reports for the design, and share your design with colleagues.
5. Get more information about WEBENCH tools at [www.ti.com/webench](http://www.ti.com/webench).

### 8.2.1.2.2 Power Inductor Selection

The inductor is one of the two energy storage elements in a boost converter. [Figure 32](#) shows how the inductor current varies during a switching cycle. The current through an inductor is quantified as:

$$V_L(t) = L \frac{di_L(t)}{dt} \quad (8)$$



**Figure 32. A. Inductor Current B. Diode Current C. Switch Current**

If  $V_L(t)$  is constant,  $di_L(t)/dt$  must be constant. Hence, for a given input voltage and output voltage, the current in the inductor changes at a constant rate.

The important quantities in determining a proper inductance value are  $\bar{I}_L$  (the average inductor current) and  $\Delta i_L$  (the inductor current ripple). If  $\Delta i_L$  is larger than  $\bar{I}_L$ , the inductor current will drop to zero for a portion of the cycle and the converter will operate in discontinuous conduction mode. If  $\Delta i_L$  is smaller than  $\bar{I}_L$ , the inductor current will stay above zero and the converter will operate in continuous conduction mode. All the analysis in this datasheet assumes operation in continuous conduction mode. To operate in continuous conduction mode, the following conditions must be met:

$$I_L > \Delta i_L \quad (9)$$

$$\frac{I_{OUT}}{1-D} > \frac{DV_{IN}}{2f_s L} \quad (10)$$

$$L > \frac{D(1-D)V_{IN}}{2I_{OUT}f_s} \quad (11)$$

Choose the minimum  $I_{OUT}$  to determine the minimum  $L$ . A common choice is to set  $\Delta i_L$  to 30% of  $\bar{I}_L$ . Choosing an appropriate core size for the inductor involves calculating the average and peak currents expected through the inductor. In a boost converter,

$$\bar{I}_L = \frac{I_{OUT}}{1-D} \quad (12)$$

$$\text{and } I_{L\_peak} = \bar{I}_L(\max) + \Delta i_L(\max),$$

where

$$\Delta i_L = \frac{DV_{IN}}{2f_s L} \quad (13)$$

A core size with ratings higher than these values should be chosen. If the core is not properly rated, saturation will dramatically reduce overall efficiency.

The LM3488 can be set to switch at very high frequencies. When the switching frequency is high, the converter can be operated with very small inductor values. With a small inductor value, the peak inductor current can be extremely higher than the output currents, especially under light load conditions.

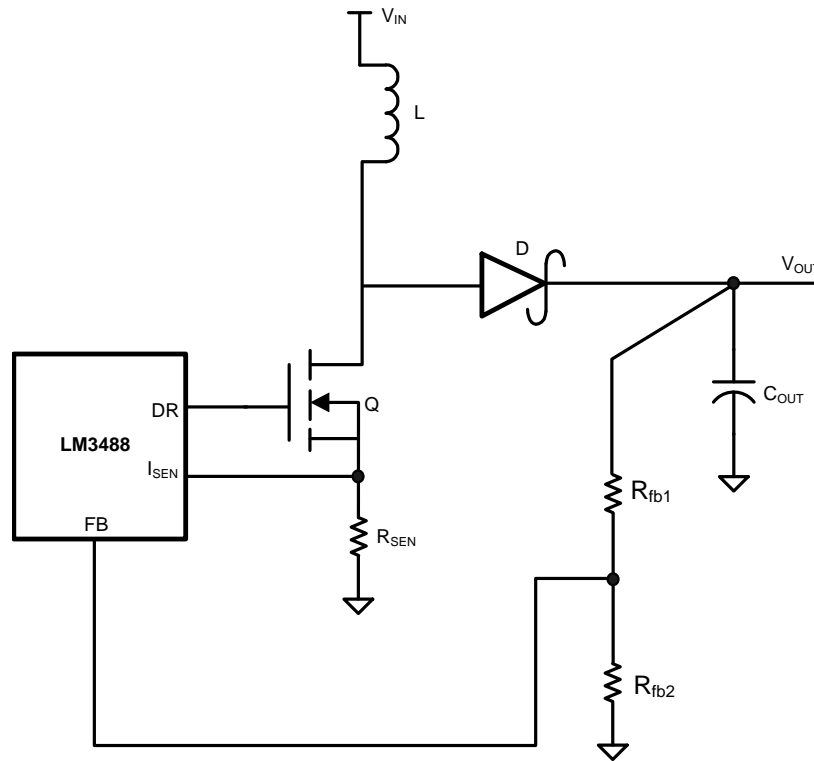
The LM3488 senses the peak current through the switch. The peak current through the switch is the same as the peak current calculated above.

### 8.2.1.2.3 Programming the Output Voltage

The output voltage can be programmed using a resistor divider between the output and the feedback pins, as shown in [Figure 33](#). The resistors are selected such that the voltage at the feedback pin is 1.26V.  $R_{F1}$  and  $R_{F2}$  can be selected using the equation,

$$V_{OUT} = 1.26 \left( 1 + \frac{R_{F1}}{R_{F2}} \right) \quad (14)$$

A 100-pF capacitor may be connected between the feedback and ground pins to reduce noise.


**Figure 33. Adjusting the Output Voltage**

#### 8.2.1.2.4 Setting the Current Limit

The maximum amount of current that can be delivered to the load is set by the sense resistor,  $R_{SEN}$ . Current limit occurs when the voltage that is generated across the sense resistor equals the current sense threshold voltage,  $V_{SENSE}$ . When this threshold is reached, the switch will be turned off until the next cycle. Limits for  $V_{SENSE}$  are specified in [Electrical Characteristics](#).  $V_{SENSE}$  represents the maximum value of the internal control signal  $V_{CS}$ . This control signal, however, is not a constant value and changes over the course of a period as a result of the internal compensation ramp (see [Figure 20](#)). Therefore the current limit threshold will also change. The actual current limit threshold is a function of the sense voltage ( $V_{SENSE}$ ) and the internal compensation ramp:

$$R_{SEN} \times ISW_{LIMIT} = V_{CS_{MAX}} = V_{SENSE} - (D \times V_{SL})$$

where

- $ISW_{LIMIT}$  is the peak switch current limit, defined by the equation below. As duty cycle increases, the control voltage is reduced as  $V_{SL}$  ramps up. Since current limit threshold varies with duty cycle, the following equation should be used to select  $R_{SEN}$  and set the desired current limit threshold: (15)

$$R_{SEN} = \frac{V_{SENSE} - (D \times V_{SL})}{ISW_{LIMIT}} \quad (16)$$

The numerator of the above equation is  $V_{CS}$ , and  $ISW_{LIMIT}$  is calculated as:

$$ISW_{LIMIT} = \left[ \frac{I_{OUT}}{(1-D)} + \frac{(D \times V_{IN})}{(2 \times f_s \times L)} \right] \quad (17)$$

To avoid false triggering, the current limit value should have some margin above the maximum operating value, typically 120%. Values for both  $V_{SENSE}$  and  $V_{SL}$  are specified in [Electrical Characteristics](#). However, calculating with the limits of these two specs could result in an unrealistically wide current limit or  $R_{SEN}$  range. Therefore, the following equation is recommended, using the  $V_{SL}$  ratio value given in [Electrical Characteristics](#):

$$R_{SEN} = \frac{V_{SENSE} - (D \times V_{SENSE} \times V_{SLratio})}{ISW_{LIMIT}} \quad (18)$$

$R_{SEN}$  is part of the current mode control loop and has some influence on control loop stability. Therefore, once the current limit threshold is set, loop stability must be verified. To verify stability, use the following equation:

$$R_{SEN} < \frac{2 \times V_{SL} \times f_S \times L}{V_O - (2 \times V_{IN})} \quad (19)$$

If the selected  $R_{SEN}$  is greater than this value, additional slope compensation must be added to ensure stability, as described in [Current Limit with External Slope Compensation](#).

#### 8.2.1.2.5 Current Limit with External Slope Compensation

$R_{SL}$  is used to add additional slope compensation when required. It is not necessary in most designs and  $R_{SL}$  should be no larger than necessary. Select  $R_{SL}$  according to the following equation:

$$R_{SL} > \frac{\frac{R_{SEN} \times (V_O - 2V_{IN})}{2 \times f_S \times L} - V_{SL}}{40 \mu A}$$

where

- $R_{SEN}$  is the selected value based on current limit. With  $R_{SL}$  installed, the control signal includes additional external slope to stabilize the loop, which will also have an effect on the current limit threshold. Therefore, the current limit threshold must be re-verified, as illustrated in the equations below : (20)

$$V_{CS} = V_{SENSE} - (D \times (V_{SL} + \Delta V_{SL}))$$

where

- $\Delta V_{SL}$  is the additional slope compensation generated and calculated as: (21)

$$\Delta V_{SL} = 40 \mu A \times R_{SL} \quad (22)$$

This changes the equation for current limit (or  $R_{SEN}$ ) to:

$$ISW_{LIMIT} = \frac{V_{SENSE} - (D \times (V_{SL} + \Delta V_{SL}))}{R_{SEN}} \quad (23)$$

The  $R_{SEN}$  and  $R_{SL}$  values may have to be calculated iteratively in order to achieve both the desired current limit and stable operation. In some designs  $R_{SL}$  can also help to filter noise on the ISEN pin.

If the inductor is selected such that ripple current is the recommended 30% value, and the current limit threshold is 120% of the maximum peak, a simpler method can be used to determine  $R_{SEN}$ . The equation below will provide optimum stability without RSL, provided that the above 2 conditions are met:

$$R_{SEN} = \frac{V_{SENSE}}{ISW_{LIMIT} + \left( \frac{V_O - V_i}{L \times f_s} \right) \times D} \quad (24)$$

#### 8.2.1.2.6 Power Diode Selection

Observation of the boost converter circuit shows that the average current through the diode is the average load current, and the peak current through the diode is the peak current through the inductor. The diode should be rated to handle more than its peak current. The peak diode current can be calculated using the formula:

$$I_{D(Peak)} = I_{OUT} / (1-D) + \Delta I_L \quad (25)$$

In the above equation,  $I_{OUT}$  is the output current and  $\Delta I_L$  has been defined in [Figure 32](#).

The peak reverse voltage for boost converter is equal to the regulator output voltage. The diode must be capable of handling this voltage. To improve efficiency, a low forward drop schottky diode is recommended.

#### 8.2.1.2.7 Power MOSFET Selection

The drive pin of LM3488 must be connected to the gate of an external MOSFET. In a boost topology, the drain of the external N-Channel MOSFET is connected to the inductor and the source is connected to the ground. The drive pin (DR) voltage depends on the input voltage (see the [Typical Characteristics](#) section). In most applications, a logic level MOSFET can be used. For very low input voltages, a sub-logic level MOSFET should be used.

The selected MOSFET directly controls the efficiency. The critical parameters for selection of a MOSFET are:

1. Minimum threshold voltage,  $V_{TH(MIN)}$
2. On-resistance,  $R_{DS(ON)}$
3. Total gate charge,  $Q_g$
4. Reverse transfer capacitance,  $C_{RSS}$
5. Maximum drain to source voltage,  $V_{DS(MAX)}$

The off-state voltage of the MOSFET is approximately equal to the output voltage.  $V_{DS(MAX)}$  of the MOSFET must be greater than the output voltage. The power losses in the MOSFET can be categorized into conduction losses and ac switching or transition losses.  $R_{DS(ON)}$  is needed to estimate the conduction losses. The conduction loss,  $P_{COND}$ , is the  $I^2R$  loss across the MOSFET. The maximum conduction loss is given by:

$$P_{COND(MAX)} = \left[ \left( \frac{I_{OUT}}{1-D_{MAX}} \right)^2 + \left( \frac{\Delta I}{3} \right)^2 \right] D_{MAX} R_{DS(ON)}$$

where

- $D_{MAX}$  is the maximum duty cycle.

(26)

$$D_{MAX} = \left( 1 - \frac{V_{IN(MIN)}}{V_{OUT}} \right)$$

(27)

The turn-on and turn-off transitions of a MOSFET require times of tens of nano-seconds.  $C_{RSS}$  and  $Q_g$  are needed to estimate the large instantaneous power loss that occurs during these transitions.

The amount of gate current required to turn the MOSFET on can be calculated using the formula:



$$I_G = Q_g \cdot F_S \quad (28)$$

The required gate drive power to turn the MOSFET on is equal to the switching frequency times the energy required to deliver the charge to bring the gate charge voltage to  $V_{DR}$  (see the [Electrical Characteristics](#) table and the [Typical Characteristics](#) section for the drive voltage specification).

$$P_{Drive} = F_S \cdot Q_g \cdot V_{DR} \quad (29)$$

#### 8.2.1.2.8 Input Capacitor Selection

Due to the presence of an inductor at the input of a boost converter, the input current waveform is continuous and triangular, as shown in [Figure 32](#). The inductor ensures that the input capacitor sees fairly low ripple currents. However, as the input capacitor gets smaller, the input ripple goes up. The rms current in the input capacitor is given by:

$$I_{CIN(RMS)} = \Delta i_L / \sqrt{3} = \frac{1}{2\sqrt{3}} \left( \frac{V_{OUT} - V_{IN}}{V_{OUT} L f_S} \right) \quad (30)$$

The input capacitor should be capable of handling the rms current. Although the input capacitor is not as critical in a boost application, low values can cause impedance interactions. Therefore a good quality capacitor should be chosen in the range of 10  $\mu F$  to 20  $\mu F$ . If a value lower than 10 $\mu F$  is used, then problems with impedance interactions or switching noise can affect the LM3488. To improve performance, especially with  $V_{IN}$  below 8 volts, it is recommended to use a 20 $\Omega$  resistor at the input to provide a RC filter. The resistor is placed in series with the  $V_{IN}$  pin with only a bypass capacitor attached to the  $V_{IN}$  pin directly (see [Figure 34](#)). A 0.1- $\mu F$  or 1- $\mu F$  ceramic capacitor is necessary in this configuration. The bulk input capacitor and inductor will connect on the other side of the resistor with the input power supply.

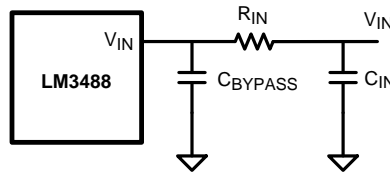


Figure 34. Reducing IC Input Noise

#### 8.2.1.2.9 Output Capacitor Selection

The output capacitor in a boost converter provides all the output current when the inductor is charging. As a result it sees very large ripple currents. The output capacitor should be capable of handling the maximum rms current. The rms current in the output capacitor is:

$$I_{COUT(RMS)} = \sqrt{(1-D) \left[ I_{OUT}^2 \frac{D}{(1-D)^2} + \frac{\Delta i_L^2}{3} \right]} \quad (31)$$

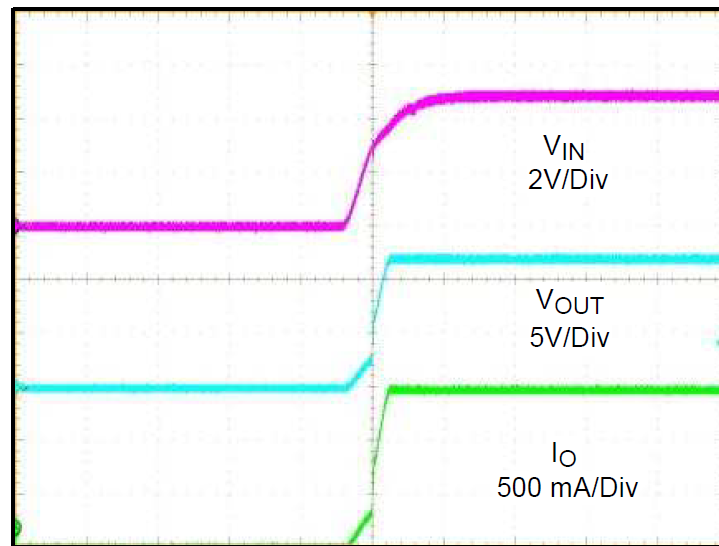
Where

$$\Delta i_L = \frac{D V_{IN}}{2 L f_S} \quad (32)$$

and D, the duty cycle is equal to  $(V_{OUT} - V_{IN})/V_{OUT}$ .

The ESR and ESL of the output capacitor directly control the output ripple. Use capacitors with low ESR and ESL at the output for high efficiency and low ripple voltage. Surface Mount tantalums, surface mount polymer electrolytic and polymer tantalum, Sanyo- OSCON, or multi-layer ceramic capacitors are recommended at the output.

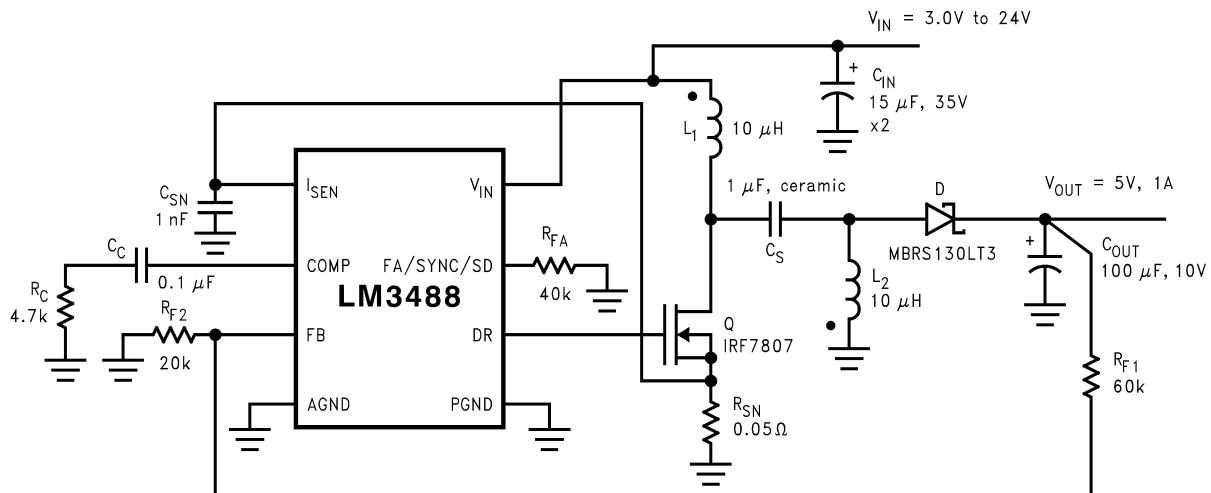
### 8.2.1.3 Application Curve



**Figure 35. Typical Startup Waveform (horizontal scale: 10ms/DIV)**

### 8.2.2 Designing SEPIC Using LM3488

Since the LM3488 controls a low-side N-Channel MOSFET, it can also be used in SEPIC (Single Ended Primary Inductance Converter) applications. An example of SEPIC using LM3488 is shown in Figure 36. As shown in Figure 36, the output voltage can be higher or lower than the input voltage. The SEPIC uses two inductors to step-up or step-down the input voltage. The inductors L1 and L2 can be two discrete inductors or two windings of a coupled transformer since equal voltages are applied across the inductor throughout the switching cycle. Using two discrete inductors allows use of catalog magnetics, as opposed to a custom transformer. The input ripple can be reduced along with size by using the coupled windings of transformer for L1 and L2.



**Figure 36. Typical SEPIC Converter**

Due to the presence of the inductor L1 at the input, the SEPIC inherits all the benefits of a boost converter. One main advantage of SEPIC over boost converter is the inherent input to output isolation. The capacitor C\_S isolates the input from the output and provides protection against shorted or malfunctioning load. Hence, the A SEPIC is useful for replacing boost circuits when true shutdown is required. This means that the output voltage falls to 0V when the switch is turned off. In a boost converter, the output can only fall to the input voltage minus a diode drop.

The duty cycle of a SEPIC is given by:

$$D = \frac{V_{OUT} + V_{DIODE}}{V_{OUT} + V_{IN} - V_Q + V_{DIODE}} \quad (33)$$

In the above equation,  $V_Q$  is the on-state voltage of the MOSFET,  $Q$ , and  $V_{DIODE}$  is the forward voltage drop of the diode.

### 8.2.2.1 Design Requirements

To calculate component values for a SEPIC converter, the power supply parameters shown in [Table 3](#) should be known. The design shown in [Figure 36](#) is the result of starting with example values shown in [Table 3](#)

**Table 3. SEPIC Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	3 V to 24 V
Output voltage	5 V
Maximum current	1 A
Operating frequency	350 kHz
Max peak to peak output ripple	200 mV

### 8.2.2.2 Detailed Design Procedure

#### 8.2.2.2.1 Power MOSFET Selection

As in boost converter, the parameters governing the selection of the MOSFET are the minimum threshold voltage,  $V_{TH(MIN)}$ , the on-resistance,  $R_{DS(ON)}$ , the total gate charge,  $Q_g$ , the reverse transfer capacitance,  $C_{RSS}$ , and the maximum drain to source voltage,  $V_{DS(MAX)}$ . The peak switch voltage in a SEPIC is given by:

$$V_{SW(PEAK)} = V_{IN} + V_{OUT} + V_{DIODE} \quad (34)$$

The selected MOSFET should satisfy the condition:

$$V_{DS(MAX)} > V_{SW(PEAK)} \quad (35)$$

The peak switch current is given by:

$$I_{SW(PEAK)} = I_{L1(AVG)} + I_{OUT} + \frac{\Delta I_{L1} + \Delta I_{L2}}{2} \quad (36)$$

The rms current through the switch is given by:

$$I_{SWRMS} = \sqrt{\left[ I_{SWPEAK}^2 - I_{SWPEAK} (\Delta I_{L1} + \Delta I_{L2}) + \frac{(\Delta I_{L1} + \Delta I_{L2})^2}{3} \right] D} \quad (37)$$

#### 8.2.2.2.2 Power Diode Selection

The Power diode must be selected to handle the peak current and the peak reverse voltage. In a SEPIC, the diode peak current is the same as the switch peak current. The off-state voltage or peak reverse voltage of the diode is  $V_{IN} + V_{OUT}$ . Similar to the boost converter, the average diode current is equal to the output current. Schottky diodes are recommended.

#### 8.2.2.2.3 Selection Of Inductors L1 and L2

Proper selection of the inductors L1 and L2 to maintain constant current mode requires calculations of the following parameters.

Average current in the inductors:

$$I_{L1AVE} = \frac{DI_{OUT}}{1-D} \quad (38)$$

$$I_{L2AVE} = I_{OUT} \quad (39)$$

Peak to peak ripple current, to calculate core loss if necessary:

$$\Delta I_{L1} = \frac{(V_{IN} - V_O) D}{(L1)f_s} \quad (40)$$

$$\Delta I_{L2} = \frac{(V_{IN} - V_O) D}{(L2)f_s} \quad (41)$$

maintains the condition  $I_L > \Delta I_L/2$  to ensure constant current mode.

$$L1 > \frac{(V_{IN} - V_O)(1-D)}{2I_{OUT}f_s} \quad (42)$$

$$L2 > \frac{(V_{IN} - V_O)D}{2I_{OUT}f_s} \quad (43)$$

Peak current in the inductor, to ensure the inductor does not saturate:

$$I_{L1PK} = \frac{DI_{OUT}}{1-D} + \frac{\Delta I_{L1}}{2} \quad (44)$$

$$I_{L2PK} = I_{OUT} + \frac{\Delta I_{L2}}{2} \quad (45)$$

$I_{L1PK}$  must be lower than the maximum current rating set by the current sense resistor.

The value of L1 can be increased above the minimum recommended to reduce input ripple and output ripple. However, once  $D_{IL1}$  is less than 20% of  $I_{L1AVE}$ , the benefit to output ripple is minimal.

By increasing the value of L2 above the minimum recommended,  $\Delta I_{L2}$  can be reduced, which in turn will reduce the output ripple voltage:

$$\Delta V_{OUT} = \left( \frac{I_{OUT}}{1-D} + \frac{\Delta I_{L2}}{2} \right) ESR$$

where

- ESR is the effective series resistance of the output capacitor. (46)

If L1 and L2 are wound on the same core, then  $L1 = L2 = L$ . All the equations above will hold true if the inductance is replaced by 2L. A good choice for transformer with equal turns is Coiltronics CTX series Octopack.

#### 8.2.2.2.4 Sense Resistor Selection

The peak current through the switch,  $I_{SW(PEAK)}$  can be adjusted using the current sense resistor,  $R_{SEN}$ , to provide a certain output current. Resistor  $R_{SEN}$  can be selected using the formula:

$$R_{SEN} = \frac{V_{SENSE} - D(V_{SL} + \Delta V_{SL})}{I_{SWPEAK}} \quad (47)$$

#### 8.2.2.2.5 SEPIC Capacitor Selection

The selection of SEPIC capacitor, CS, depends on the rms current. The rms current of the SEPIC capacitor is given by:

$$I_{CSRMS} = \sqrt{I_{SWRMS}^2 + (I_{L1PK}^2 - I_{L1PK}\Delta I_{L1} + \Delta I_{L1}^2)(1-D)} \quad (48)$$

The SEPIC capacitor must be rated for a large ACrms current relative to the output power. This property makes the SEPIC much better suited to lower power applications where the rms current through the capacitor is relatively small (relative to capacitor technology). The voltage rating of the SEPIC capacitor must be greater than the maximum input voltage. Tantalum capacitors are the best choice for SMT, having high rms current ratings relative to size. Ceramic capacitors could be used, but the low C values will tend to cause larger changes in voltage across the capacitor due to the large currents. High C value ceramics are expensive. Electrolytics work well for through hole applications where the size required to meet the rms current rating can be accommodated. There is an energy balance between CS and L1, which can be used to determine the value of the capacitor. The basic energy balance equation is:

$$\frac{1}{2} C_S \Delta V_S^2 = \frac{1}{2} L_1 \Delta I_{L1}^2 \quad (49)$$

Where

$$\Delta V_S = \left( \frac{V_{OUT}}{V_{OUT} + V_{IN} - V_Q + V_{DIODE}} \right) \frac{I_{OUT}}{f_s C_S} \quad (50)$$

is the ripple voltage across the SEPIC capacitor, and

$$\Delta I_{L1} = \frac{(V_{IN} - V_Q) D}{L_1 f_s} \quad (51)$$

is the ripple current through the inductor L1. The energy balance equation can be solved to provide a minimum value for CS:

$$C_S \geq L_1 \frac{I_{OUT}^2}{(V_{IN} - V_Q)^2} \quad (52)$$

#### 8.2.2.2.6 Input Capacitor Selection

Similar to a boost converter, the SEPIC has an inductor at the input. Hence, the input current waveform is continuous and triangular. The inductor ensures that the input capacitor sees fairly low ripple currents. However, as the input capacitor gets smaller, the input ripple goes up. The rms current in the input capacitor is given by:

$$I_{CIN(RMS)} = \Delta I_{L1} / \sqrt{2} = \frac{D}{2\sqrt{3}} \left( \frac{V_{IN} - V_Q}{L_1 f_s} \right) \quad (53)$$

The input capacitor should be capable of handling the rms current. Although the input capacitor is not as critical in a boost application, low values can cause impedance interactions. Therefore a good quality capacitor should be chosen in the range of 10µF to 20µF. If a value lower than 10µF is used, then problems with impedance interactions or switching noise can affect the LM3488. To improve performance, especially with VIN below 8 volts, it is recommended to use a 20Ω resistor at the input to provide a RC filter. The resistor is placed in series with the VIN pin with only a bypass capacitor attached to the VIN pin directly (see [Figure 34](#)). A 0.1µF or 1µF ceramic capacitor is necessary in this configuration. The bulk input capacitor and inductor will connect on the other side of the resistor with the input power supply.

#### 8.2.2.2.7 Output Capacitor Selection

The ESR and ESL of the output capacitor directly control the output ripple. Use low capacitors with low ESR and ESL at the output for high efficiency and low ripple voltage. Surface mount tantalums, surface mount polymer electrolytic and polymer tantalum, Sanyo- OSCON, or multi-layer ceramic capacitors are recommended at the output.

The output capacitor of the SEPIC sees very large ripple currents (similar to the output capacitor of a boost converter). The rms current through the output capacitor is given by:

$$I_{RMS} = \sqrt{\frac{[I_{SWPK}^2 - I_{SWPK} (\Delta I_{L1} + \Delta I_{L2}) + \frac{(\Delta I_{L1} + \Delta I_{L2})^2}{3}] (1-D) - I_{OUT}^2}{3}} \quad (54)$$

The ESR and ESL of the output capacitor directly control the output ripple. Use low capacitors with low ESR and ESL at the output for high efficiency and low ripple voltage. Surface mount tantalums, surface mount polymer electrolytic and polymer tantalum, Sanyo- OSCON, or multi-layer ceramic capacitors are recommended at the output for low ripple.

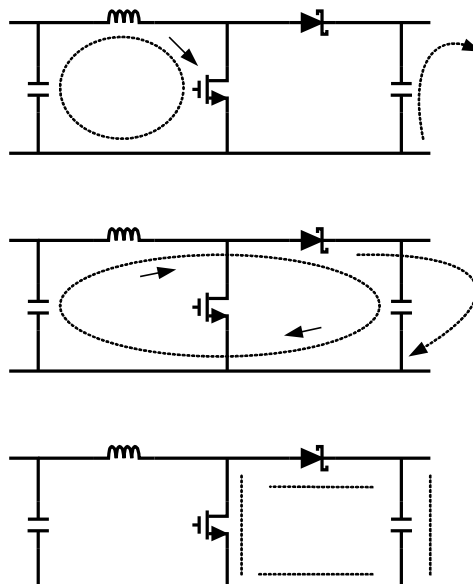
## 9 Power Supply Recommendations

The LM3488 is designed to operate from various DC power supply including a car battery. If so, VIN input should be protected from reversal voltage and voltage dump over 48 Volts. The impedance of the input supply rail should be low enough that the input current transient does not cause drop below VIN UVLO level. If the input supply is connected by using long wires, additional bulk capacitance may be required in addition to normal input capacitor.

## 10 Layout

### 10.1 Layout Guidelines

Good board layout is critical for switching controllers such as the LM3488. First the ground plane area must be sufficient for thermal dissipation purposes and second, appropriate guidelines must be followed to reduce the effects of switching noise. Switch mode converters are very fast switching devices. In such devices, the rapid increase of input current combined with the parasitic trace inductance generates unwanted  $Ldi/dt$  noise spikes. The magnitude of this noise tends to increase as the output current increases. This parasitic spike noise may turn into electromagnetic interference (EMI), and can also cause problems in device performance. Therefore, care must be taken in layout to minimize the effect of this switching noise. The current sensing circuit in current mode devices can be easily effected by switching noise. This noise can cause duty cycle jitter which leads to increased spectral noise. The most important layout rule is to keep the AC current loops as small as possible. [Figure 37](#) shows the current flow of a boost converter. The top schematic shows a dotted line which represents the current flow during onstate and the middle schematic shows the current flow during off-state. The bottom schematic shows the currents we refer to as AC currents. They are the most critical ones since current is changing in very short time periods. The dotted lined traces of the bottom schematic are the once to make as short as possible.



**Figure 37. Current Flow in a Boost Application**

## Layout Guidelines (continued)

The PGND and AGND pins have to be connected to the same ground very close to the IC. To avoid ground loop currents attach all the grounds of the system only at one point. A ceramic input capacitor should be connected as close as possible to the Vin pin and grounded close to the GND pin. For a layout example please see AN-1204 LM378/LM3488 Evaluation Board (SNVA656A). For more information about layout in switch mode power supplies please refer to AN-1229 SIMPLE SWITCHER® PCB Layout Guidelines (SNVA054c).

## 10.2 Layout Example

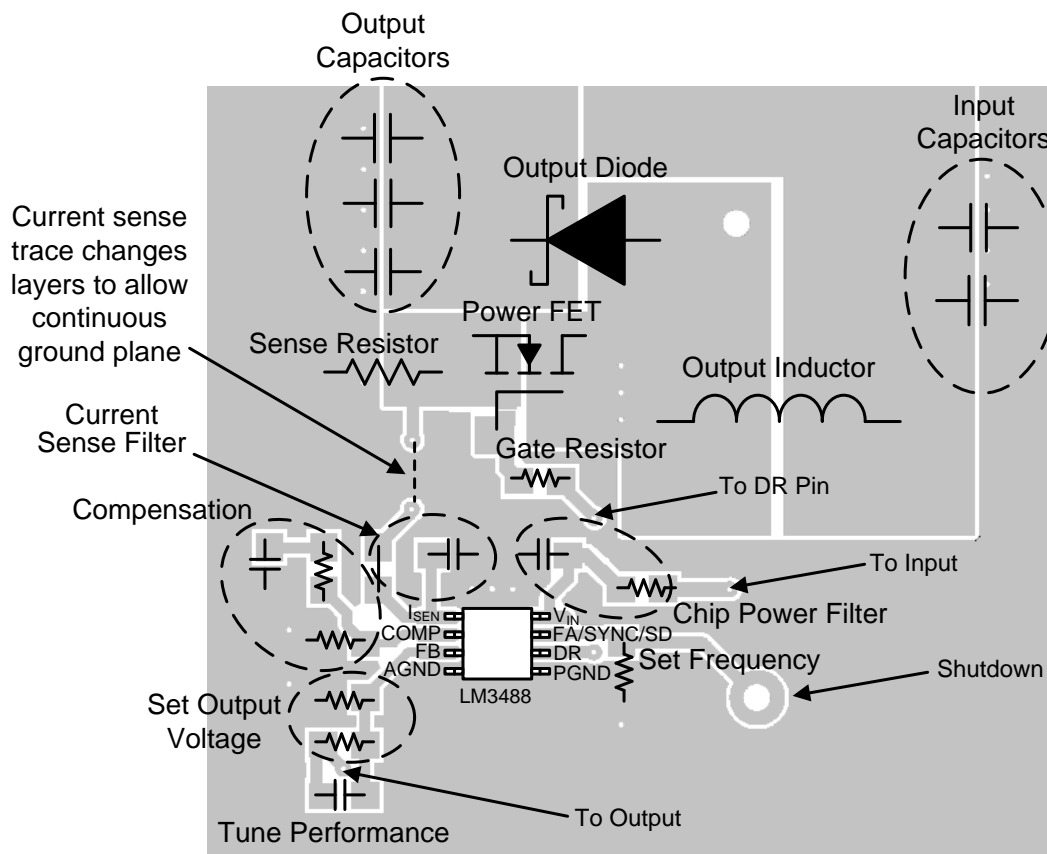


Figure 38. Example Layout of a Boost Application using LM3488

## 11 Device and Documentation Support

### 11.1 Custom Design with WEBENCH Tools

[Click here](#) to create a custom design using the LM3488 device with the WEBENCH® Power Designer.

1. Start by entering your  $V_{IN}$ ,  $V_{OUT}$  and  $I_{OUT}$  requirements.
2. Optimize your design for key parameters like efficiency, footprint and cost using the optimizer dial and compare this design with other possible solutions from Texas Instruments.
3. WEBENCH Power Designer provides you with a customized schematic along with a list of materials with real time pricing and component availability.
4. In most cases, you will also be able to:
  - Run electrical simulations to see important waveforms and circuit performance,
  - Run thermal simulations to understand the thermal performance of your board,
  - Export your customized schematic and layout into popular CAD formats,
  - Print PDF reports for the design, and share your design with colleagues.

## Custom Design with WEBENCH Tools (continued)

- Get more information about WEBENCH tools at [www.ti.com/webench](http://www.ti.com/webench).

### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 4. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM3488	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
LM3488-Q1	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 11.4 Trademarks

WEBENCH is a registered trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">LM3488MM</a>	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MM.A	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MM.B	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	No	SNPB	Level-1-260C-UNLIM	-40 to 125	S21B
<a href="#">LM3488MM/NOPB</a>	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	Yes	NIPDAUAG   SN	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MM/NOPB.A	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MM/NOPB.B	Active	Production	VSSOP (DGK)   8	1000   SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S21B
<a href="#">LM3488MMX/NOPB</a>	Active	Production	VSSOP (DGK)   8	3500   LARGE T&R	Yes	NIPDAUAG   SN	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MMX/NOPB.A	Active	Production	VSSOP (DGK)   8	3500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S21B
LM3488MMX/NOPB.B	Active	Production	VSSOP (DGK)   8	3500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S21B

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM3488MM/NOPB	VSSOP	DGK	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM3488MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM3488MM/NOPB	VSSOP	DGK	8	1000	208.0	191.0	35.0
LM3488MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0

**DGK0008A****PACKAGE OUTLINE****VSSOP - 1.1 mm max height**

SMALL OUTLINE PACKAGE



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**NOTES:**

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

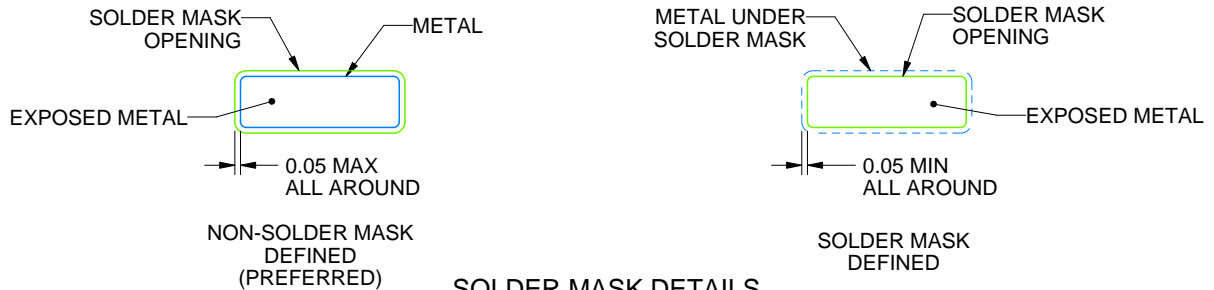
DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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